AMENDMENTS TO CLAIMS

Claims 1-28 were previously canceled. Claims 29-32 were previously presented. New claims 33-44 are added.

1.-28. (Cancelled)

29. (Previously Presented) A wordline voltage control system for raising a voltage of a wordline to a predetermined voltage and maintaining the voltage of the wordline at the predetermined voltage, comprising:

a wordline extending across a portion of a non-volatile memory array; and

a charge pump connected to the wordline to deliver current from the charge pump to the wordline, the charge pump including a stage that has variable current output according to a variable capacitance in the stage, wherein the variable capacitance has a selectable first capacitor to provide a first current from the charge pump and a second capacitor to provide a second current from the charge pump, and the first capacitor is controlled by a driver circuit and the driver circuit is protected by a driver protection circuit.

- 30. (Previously Presented) The system of claim 29 wherein the driver circuit is an adaptive driver circuit that provides voltage to the first capacitor at a selectable voltage level.
- 31. (Previously Presented) The system of claim 29 wherein the second current is approximately equal to a leakage current of the wordline.
- 32. (Previously Presented) The system of claim 29 wherein the driver circuit is responsive to a voltage detected on the wordline.
- 33. (New) A charge pump connected to a wordline of a nonvolatile memory array to deliver current to the wordline, comprising:

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a stage that has variable current output according to a variable capacitance in the stage, the variable capacitance having a selectable first capacitor to provide a first current from the charge pump and a second capacitor to provide a second current from the charge pump;

a first driver circuit connected to the first capacitor to provide electrical current to the first capacitor; and

a driver protection circuit connected to the first driver circuit.

- 34. (New) The charge pump of claim 33 wherein the first driver circuit provides electrical current to the first capacitor in a first mode and does not provide electrical current to the first capacitor in a second mode, the charge pump providing the first current in the first mode and the second current in the second mode.
- 35. (New) The charge pump of claim 34 wherein the second current is equal to the leakage current of the wordline.
- 36. (New) The charge pump of claim 35 wherein the first current is greater than the second current.
- 37. (New) The charge pump of claim 34 wherein the driver protection circuit comprises a transistor that regulates a voltage at an output of the first driver circuit in the second mode.
- 38. (New) The charge pump of claim 37 wherein the driver protection circuit further comprises a resistor connected to the transistor.
- 39. (New) The charge pump of claim 33 further comprising a second driver circuit connected to the second capacitor.
- 40. (New) The charge pump of claim 33 further comprising additional stages that provide increased voltage.

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- 41. (New) The charge pump of claim 33 wherein the first driver circuit is an adaptive driver circuit that provides electrical current at a variable controlled voltage.
- 42. (New) A charge pump connected to a nonvolatile memory array, comprising: a stage that has variable current output according to a variable capacitance in the stage, the variable capacitance having a selectable first capacitor to provide a first current from the charge pump and a second capacitor to provide a second current from the charge pump;

an adaptive driver circuit connected to the first capacitor to provide electrical current to the first capacitor at a voltage selected from a voltage range; and

a driver protection circuit connected to the first driver circuit.

- 43. (New) The charge pump of claim 42 wherein the adaptive driver circuit provides a first voltage in a first mode and a second voltage in a second mode, the charge pump providing a first current in the first mode and a second current in the second mode.
- 44. (New) The charge pump of claim 43 wherein the charge pump switches from the first mode to the second mode in response to a voltage measured in the nonvolatile memory array.

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